

Pin Descriptions

Pin Number	Pin Name	Function	
1	DSA	Serial Data Input	
2	DSB	Serial Data Input	
3	Q0	Data Output	
4	Q1	Data Output	
5	Q2	Data Output	
6	Q3	Data Output	
7	GND	Ground	
8	CP	Clock Pulse –Positive Edge Triggered	
9	MR	Master Reset - Asynchronous	
10	Q4	Data Output	
11	Q5	Data Output	
12	Q6	Data Output	
13	Q7	Data Output	
14	Vcc	Supply Voltage	

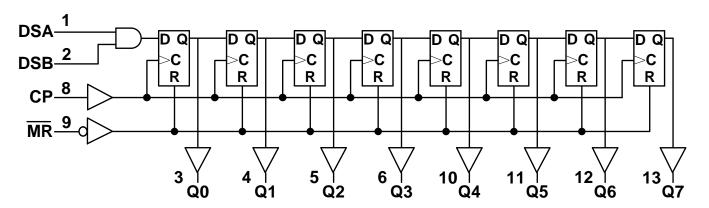
Function Table (Note 4)

		In	Output			
Mode	MR	СР	DSA	DSB	Q0	Q1-Q7
Reset	L	Х	Х	Х	L	L
	Н	↑	L	Х	L	Qn←Qn-1 (n= 1 to7)
Shift	Н	↑	Х	L	L	Qn←Qn-1 (n= 1 to7)
	Н	↑	Н	Н	Н	Qn←Qn-1 (n= 1 to7)

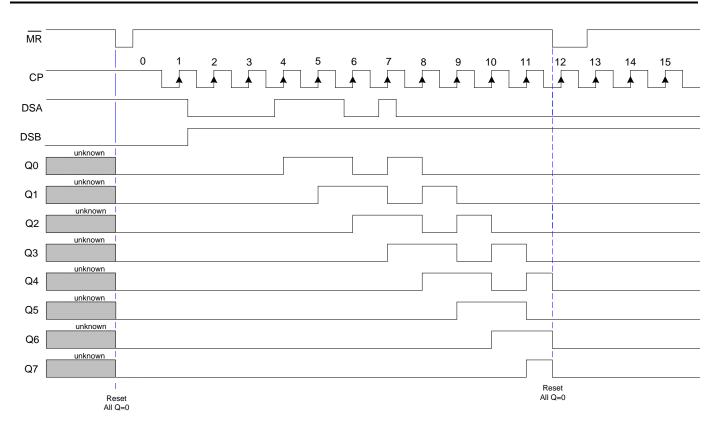
Note: 4. Signals asserted on DSA and DSB must be in place longer than Tsu (set up time) before CP occurs and remain in place Thold (hold time) after CP.



Logic Diagram



Timing Diagram



Notes: 5. All Q values are reset to LOW when $\overline{\text{MR}}$ goes low. $\overline{\text{MR}}$ is asynchronous and overrides all other signals.

6. Serial data supplied at DSA and DSB is ANDED and transferred to Q0 on positive edge of CP.



Absolute Maximum Ratings (Note 7) ($T_A = +25^{\circ}C$, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 8)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
lok	Output Clamp Current V _O < -0.5V or V _O > V _{CC} +0.5V	±20	mA
Io	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	±25	mA
I _{CC}	Continuous Current Through Vcc	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes:

Recommended Operating Conditions (Note 9) (T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	-	2.0	5.5	V
VI	Input Voltage	-	0	5.5	V
Vo	Output Voltage	-	0	V _{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 3.0V \text{ to } 3.6V$	-	100	ns/V
ΔυΔν	Imput Transition Rise of Fall Rate	V _{CC} = 4.5V to 5.5V	-	20	115/V
TA	Operating Free-Air Temperature	-	-40	+125	°C

Note: 9. Unused inputs should be held at V_{CC} or Ground.

^{7.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

be within recommend values.

8. Input Voltage cannot exceed Vcc to the extent the Maximum clamp current is exceeded.



Electrical Characteristics ($T_A = +25^{\circ}C$, unless otherwise specified.)

Symbol	Symbol Parameter		V _{CC}	Т	_A = +25°C			0°C to 5°C	T _A = -40°C	to +125°C	Unit
-		Conditions		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
	I Park I accel		2.0V	1.5	-	-	1.5	-	1.5	-	
V_{IH}	High-Level Input Voltage	-	3.0V	2.1	-	-	2.1	-	2.1	-	V
	input voltage		5.5V	3.85	-	-	3.85	-	3.85		
	1 11		2.0V	1	-	0.5	-	0.5	-	0.5	
V_{IL}	Low-Level Input Voltage	-	3.0V	1	-	0.9	=	0.9	-	0.9	V
	input voltage		5.5V	-	-	1.65	-	1.65	-	1.65	
		$I_{OH} = -50\mu A$	2.0V	1.9	2.0	-	1.9	-	1.9	-	
		I _{OH} = -50μA	3.0V	2.9	3.0	-	2.9	-	2.9	-	
V_{OH}	High-Level Output Voltage	I _{OH} = -50μA	4.5V	4.4	4.5	-	4.4	-	4.4	-	V
	Output Voltage	$I_{OH} = -4.0 \text{mA}$	3.0V	2.58	-	-	2.48	-	2.40	-	
		I _{OH} = -8mA	4.5	3.94	-	-	3.80	-	3.70	-	
		$I_{OL} = 50\mu A$	2.0V	-	0	0.1	-	0.1	-	0.1	
		$I_{OL} = 50\mu A$	3.0V	-	0	0.1	-	0.1	-	0.1	
V_{OL}	Low-Level Output Voltage	$I_{OL} = 50\mu A$	4.5V	-	0	0.1	-	0.1	-	0.1	V
	Output voltage	I _{OL} = 4mA	3.0V	-	0.15	0.36	-	0.44	-	0.55	1
		I _{OL} = 8mA	4.5V	-	0.15	0.36	-	0.44	-	0.55	1
lı	Input Current	V _I = GND or 5.5V	0V or 5.5V	-	-	±0.1	-	± 1	-	± 2	μΑ
Icc	Supply Current	$V_1 = GND \text{ or } V_{CC}, I_0 = 0A$	5.5V	-	-	4.0	-	40	-	80	μA



Switching Characteristics

Symbol /		Test			T _A = +25°C		-40°C to	+85°C	-40°C to	+125°C	Unit
Parameter	Pins	Conditions Figure 1	V _{cc}	Min	Тур.	Max	Min	Max	Min	Max	
4		C _L = 15pF	3.0V to	80	125	-	65	-	50	-	
f _{MAX} Maximum	СР	C _L = 50pF	3.6V	50	75	-	45	-	35	-	MHz
Frequency	OI .	$C_L = 15pF$	4.5V to	125	175	-	105	-	85	-	1011 12
1 requeries		$C_L = 50pF$	5.0V	85	115	-	75	-	65	-	
	CP HIGH or	_	3.0V to 3.6V	5.0	-	-	5.0	-	5.0	-	200
t _W	LOW	-	4.5V to 5.0V	5.0	-	-	5.0	-	5.0	-	ns
Pulse Width			3.0V to 3.6V	5.0	-	-	5.0	-	5.0	-	
MR LOW	-	4.5V to 5.0V	5.0	-	-	5.0	-	5.0	-	ns	
t _{S∪}	t _{SU} DSA or Set-up Time DSB to CP		3.0V to 3.6V	5.0	-	-	6.0	-	6.0	-	
Set-up Time		-	4.5V to 5.0V	4.5	-	-	4.5	-	4.5	-	ns
t _H	DOA		3.0V to 3.6V	1.5	-	-	1.5	-	1.5	-	
Hold Time	DSA or	-	4.5V to 5.0V	2.0	-	-	2.0	-	2.0	-	ns
t _{rec}			3.0V to 3.6V	2.5	-	-	2.5	-	2.5	-	
RecoveryTime	MR to CP	-	4.5V to 5.0V	2.5	-	-	2.5	-	2.5	-	ns
		C _L = 15pF	3.0V to	-	6.5	12.8	1.0	15.0	1.0	16.0	
	00.0	C _L = 50pF	3.6V	-	9.3	16.3	1.0	18.5	1.0	20.5	
t _{PD}	CP to Qn	C _L = 15pF	4.5V to	-	4.5	9.0	1.0	10.5	1.0	11.5	ns
Propagation		C _L = 50pF	5.0V	-	6.4	11.0	1.0	12.5	1.0	14.0	
Delay		C _L = 15pF	3.0V to	-	5.3	12.8	1.0	15.0	1.0	16.0	
	 -	C _L = 50pF	3.6V	-	7.6	16.3	1.0	18.5	1.0	20.5	
	MR to Qn	C _L = 15pF	4.5V to	-	4.0	8.6	1.0	10.0	1.0	11.0	ns
		C _L = 50pF	5.0V	=	5.8	10.6	1.0	12.0	1.0	13.5	

Operating Characteristics (T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V _{CC} = 5.5	Unit	
	raiailletei	rest Conditions	Тур	Maximum	Oilit
C_{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	51	-	pF
C _I	Input Capacitance	$V_I = V_{CC}$ or GND	3	10	pF

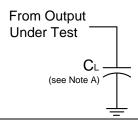
Vcc

August 2015

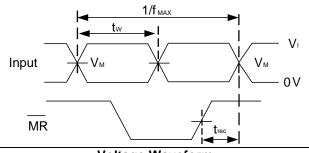
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Parameter Measurement Information

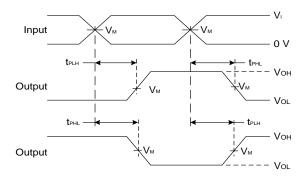


V _{CC}	Inp	outs	V _M	Cı	
	VI	t _r /t _f		J.	
3.0V-3.6V	V _{CC}	≤3ns	V _{CC} /2	15pF,50pF	
4.5V-5.5V	V _{CC}	≤3ns	V _{CC} /2	15pF,50pF	



Voltage Waveform
Pulse Duration and Recovery Time

Voltage Waveform Set-up and Hold Times



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

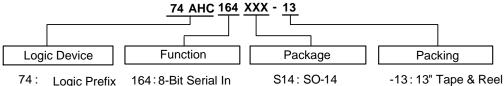
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information



74: Logic Prefix AHC: 2.0V to 5.5V Family 164:8-Bit Serial In Parallel Out Shift Register

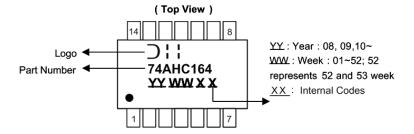
T14: TSSOP-14

T14: TSSOP-14 D14: PDIP-14

Device	Dookono Codo	Dockoning	Packing		
Device	Package Code	Packaging	Quantity	Part Number Suffix	
74AHC164S14-13	S14	SO-14	2,500/Tape & Reel	-13	
74AHC164T14-13	T14	TSSOP-14	2,500/Tape & Reel	-13	
74AHC164D14	D14	PDIP-14	Tube		

Marking Information

(1) SO-14, TSSOP-14, PDIP-14



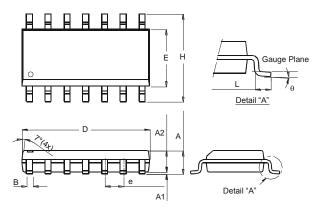
Part Number	Package
74AHC164S14-13	SO-14
74AHC164T14-13	TSSOP-14
74AHC164D14	PDIP-14



Package Outline Dimensions (All dimensions in mm.)

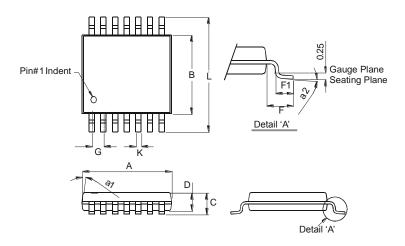
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

Package Type: SO-14



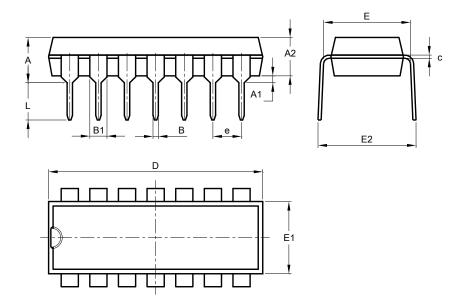
	SO-14							
Dim	Min	Max						
Α	1.47	1.73						
A1	0.10	0.25						
A2	1.45	Тур						
В	0.33	0.51						
D	8.53	8.74						
Е	3.80	3.99						
е	1.27	Тур						
H	5.80	6.20						
L	0.38	1.27						
θ	0°	8°						
All Dimensions in mm								

Package Type: TSSOP-14



	TSSOP-14						
Dim	Min	Max					
a1	7° (4X)					
a2	0°	8°					
Α	4.9	5.10					
В	4.30	4.50					
С	_	1.2					
D	0.8	1.05					
F	1.00	Тур					
F1	0.45	0.75					
G	0.65	Тур					
K	0.19	0.30					
L	L 6.40 Typ						
All Dir	nensions	s in mm					

Package Type: PDIP-14



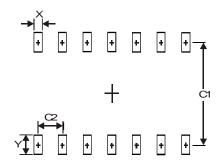
PDIP-14		
Dim	Min	Max
Α	3.710	4.310
A1	0.510	-
A2	3.200	3.600
В	0.380	0.570
B1	1.524 (BSC)	
С	0.204	0.360
D	18.800	19.200
Е	6.200	6.600
E1	7.320	7.920
E2	8.400	9.000
е	2.540 (BSC)	
Ĺ	3.000	3.600
All Dimensions in mm		



Suggested Pad Layout

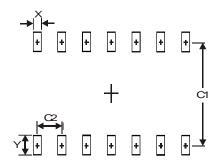
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)	
Х	0.45	
Y	1.45	
C1	5.9	
C2	0.65	



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